

View Online at <https://aerobasegroup.com/nsn/5961-00-283-1710>

Inclosure Material:

Ceramic or metal

Overall Length:

Between 0.240 inches and 0.260 inches

Overall Height:

Between 0.030 inches and 0.070 inches

Overall Width:

Between 0.140 inches and 0.260 inches

Component Name And Quantity:

8 semiconductor device diode

Mounting Method:

Terminal

Semiconductor Material:

Silicon all semiconductor device diode

Voltage Rating In Volts Per Characteristic:

40.0 working peak reverse voltage all semiconductor device diode

Current Rating Per Characteristic:

0.25 amperes forward current, total rms megahertz all semiconductor device diode and 0.33 amperes source cutoff current preset all semiconductor device diode and 0.80 amperes forward current, average blank all semiconductor device diode

Power Rating Per Characteristic:

0.40 watts small-signal input power, common-collector absolute all semiconductor

Maximum Operating Temperature Per Measurement Point:

150.0 degrees celsius ambient air

Test Data Document:

92220--511-026 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

10 pin

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fig:

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